

TDA7336

STEREO PREAMP + AMS + DOLBY B* NOISE REDUCTION PROCESSOR

- DUAL CHANNEL PROCESSOR FOR PLAY-BACK APPLICATIONS.
- STEREO DOLBY B NR SYSTEM
- LOW NOISE HEAD PREAMPLIFIER
- MUTE, AMS (AUDIO MUSIC SENSOR) FUNCTIONS
- INTERNAL SWITCHES FOR EQUALIZATION
- DOLBY REFERENCE LEVEL -6dBm (388.2mVRMS)
- MINIMUM NUMBER OF EXTERNAL COMPO-NENTS
- LOW SUPPLY CURRENT (18mA)
- MIXED BIPOLAR/CMOS TECHNOLOGY

DESCRIPTION

The TDA7336 is a monolithic BICmos IC designed for use in stereo cassette player systems.

The device includes two separate audio channels composed by low noise preamplifier, Dolby B noise reduction system and Audio Music Sensor.

The dual preamplifier contains mute, metal/normal facilities for amplification of low level signal in applications requiring very low noise performances.

Each channel consists of two cascaded operational amplifiers.

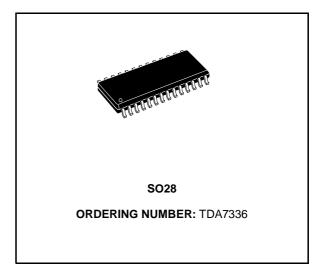
The first one, AMP1, has a fixed gain of 36dB, and allows magnetic heads connection directly to ground. The second one, AMP2, is a standard operational amplifier whose equalizing external components fix the frequency response.

The Audio Music Sensor circuit detects the interprogram space and then the starting point of musical programs (the interprogram time and program detection time are externally selectable).

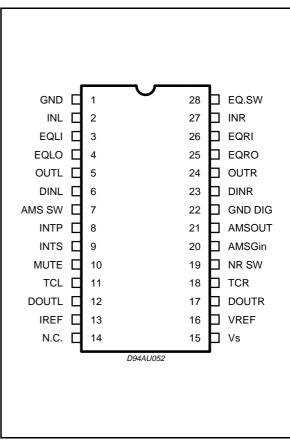
The device contains Dolby B decoder NR chains requiring very few external components and do not require coils.

* Dolby B and the Double-D symbol are trademarks of Dolby Laboratories Licensing Corporation, San Francisco, California 94103-4813, USA.

This device is available only to Licensing and application information may be obtained from Dolby Lab.



PIN CONNECTION (Top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	12	V
Ptot	Total Power Dissipation	1	W
Тор	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-40 to 150	°C

THERMAL DATA

Rth j-pins Thermal resistance junction-pins	85	°C/W
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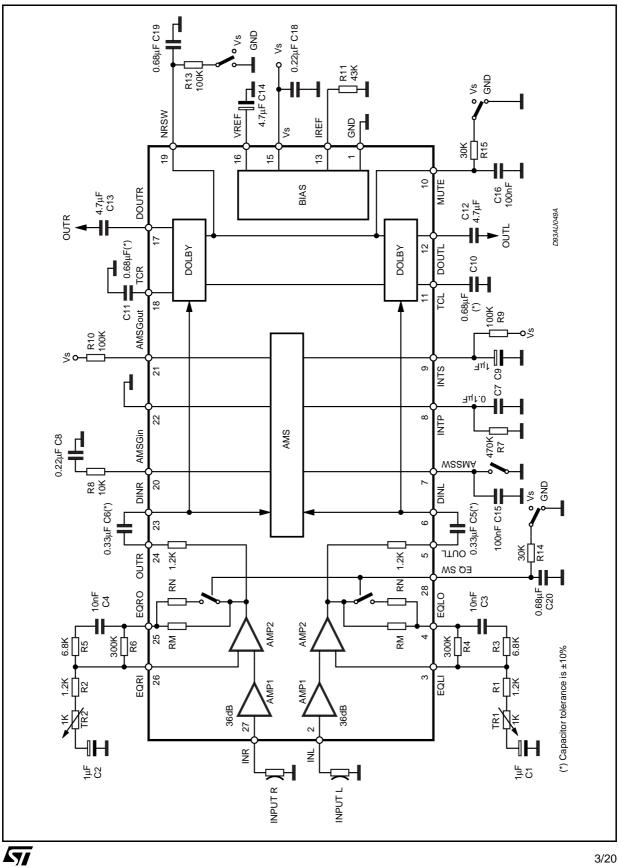
PIN FUNCTIONS

N.	Name	VDC (V)	Function	
1	GND		Ground	
2	IN L	0	Preamplifier Left Input	
3,26	EQLI, EQRI	4.6	Equalizer Inputs	
4, 25	EQLO, EQRO	4.6	Equalizer Outputs	
5, 24	OUTL, OUTR	4.6	Preamplifier Outputs	
6, 23	DINL, DINR	V _{ref}	Dolby NR Inputs	
7	AMS SW	5.6	Audio Music Sensor Switch (ON/OFF) HIGH = ON	
8	INTP		Interprogram Time Constant ("Signal Detection")	
9	INTS		Interspace Time Constant ("Blank Detection")	
10	MUTE		Mute Switch ON = LOW (2)	
11, 18	TLC, TCR	0.4	Dolby Time Constants	
12, 17	DOUTL, DOUTR	V _{ref}	Dolby Outputs	
13	Iref	1.2	Reference Current Source	
15	Vs		Positive Power Supply	
16	V _{ref}	V _S /2	Reference Voltage	
19	NR SW		Noise reduction ON/OFF: HIGH =OFF (2)	
20	AMS GIN	1.4	Audio Music Sensor Input Pin	
21	AMS OUT		Audio Music Sensor Output Pin (open collector configuration, see Fig. 2)	
22	GND DIG.	0	Digital Ground	
27	IN R	0	Preamplifier Right Input	
28	EQ SW	0	Equalizer Switch (Low = normal position High = metal position)	

(2) Internal pull-up resistor (digital high level if pin left open)



Figure 1: Application Circuit



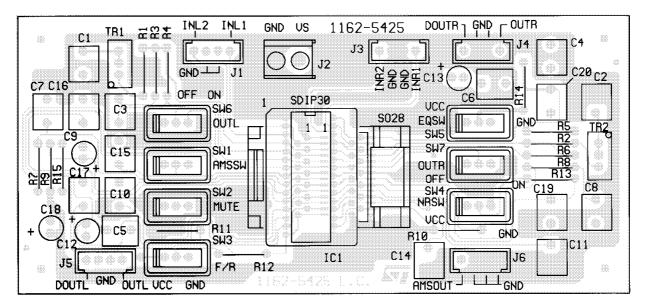
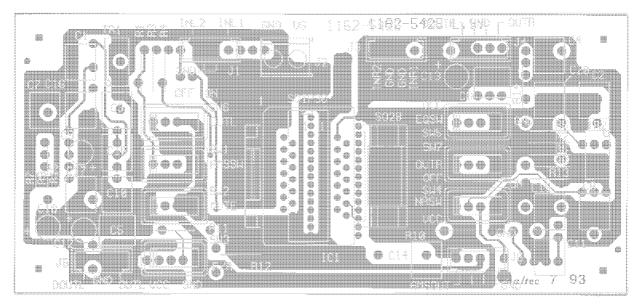
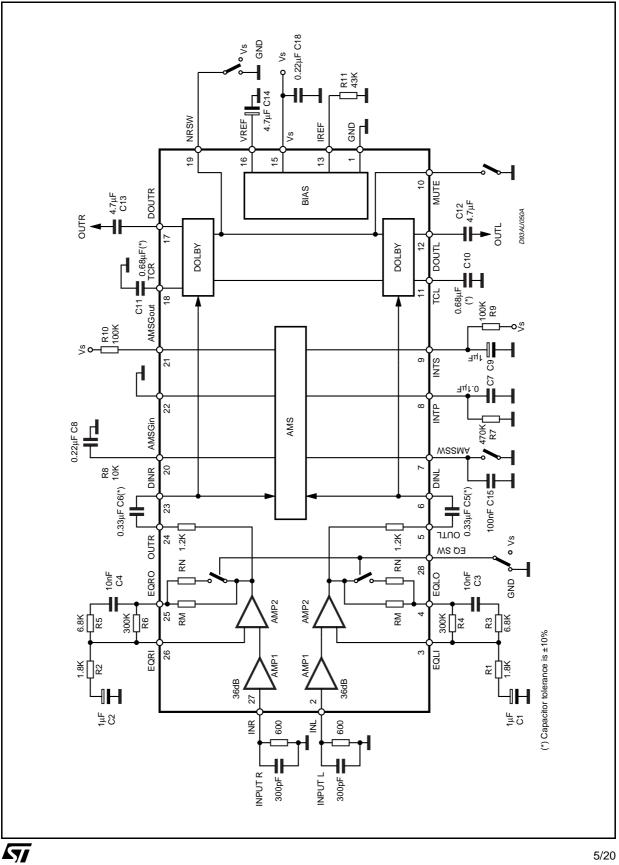


Figure 1a: Components & Top Copper Layer of the Fig. 1 (1:1 scale).

Figure 1b: Bottom Copper Layer of the Fig. 1 (1:1 scale).



TEST CIRCUIT



ELECTRICAL CHARACTERISTICS (Vs = 8.5V; f = 1KHz; R_g = 600Ω T_{amb} = 25° C; R11 = $43K\Omega$ all level referenced to -6dBm/400Hz, at Dout with NR SW OFF; unless otherwise specified see application circuit of Fig. 1) NAB METAL position.

SUPPLY

Symbol	Parameter	Test Condition		Min.	Тур.	Max.	Unit
Vs	Supply Voltage			8	8.5	10.5	V
ls	Supply Current			11	18	26	mA
Vref	Reference Voltage (pin 16)			4	4.3	4.6	V
VDC	DC Voltage pin 13 (R ₁₁ = 43K)			1.15	1.25	1.35	V
SVR	Ripple Rejection (Input Referred)	V _{ripple} = 0.3Vrms f _{ripple} = 1KHz	Dolby OFF Dolby ON	80 85	90 95		dB dB
MUTEth	Mute Threshold Pin 10	ON OFF	1	0 2.0		0.8 Vs	V V
IMUTE	Mute Current				10	20	μA
MUTEA	Mute Attenuation			55	65		dB

PREAMPLIFIER

Rı	Input Resistance	(pin 2, 27)	30	50	70	KΩ
h	Input Bias Current				10	μΑ
Gv	Closed Loop Gain	pin 3, 4 and 25, 26 shorted	32.5	35.5	38.5	dB
ΔGv	Closed Loop Gain Match		-1		1	dB
Rм	Resistance Metal Position		4.35	5.8	7.25	KΩ
RN	Resistance Normal Position		50	160	300	Ω
en	Total Input Noise	Unw. B= 20Hz to 20KHz $R_g = 0\Omega$; $R_g = 600\Omega$; A weighted $R_g = 600\Omega$;		0.45 0.8 0.5		μV μV μV
Ro	Output Impedance	(Pin 5, 24)	0.9	1.2	1.7	KΩ
EQi	Normal Low Level (pin 28)		0		1.5	V
EQh	Metal High Level (pin 28)		3.5		Vs	V
ΔR_M	Metal Resistance Matching		-2	0	+2	%

AUDIO MUSIC SENSOR

IAMSout	AMS Output Current				5	mA
VAMSout	AMS Output Low Level	IAMOUT = 2mA		200	800	mV
R _P 20	Input Impedance		0.8	1.1	1.4	KΩ
AMSswl	AMS OFF Low Level		0		0.8	V
AMSswh	AMS ON High Level		2		VS	V
Vth1	Interprogram Threshold Voltage	(pin 8)	1.2	1.45	1.7	V
VTH ₂	Interspace Threshold Voltage	(pin 9)	4	4.3	4.6	V
AMSth	AMS Threshold Level	see note (3)	0.6	1	1.4	V
IAMS _{sw}	AMS Switch pin Current		5	10	15	μΑ

DOLBY SECTION

Gv	Voltage Gain	f = 1KHz;	OFF	-1	0	1	dB
ΔGv	Gain Matching		OFF	-0.5		0.5	dB
RDi	Dolby Input Res.	(pin 6, 23)		46	63		KΩ
S/H	Signal Handling	Vs = 8V; THD = 1%	OFF	12	13		dB
R _{DO}	Dolby Output Imp.	(pin 12, 17)		100	200	300	Ω
B DEC 1	Decode Out	f = 10KHz; Vı = 0.4dB	ON	-1.5	0	1.5	dB

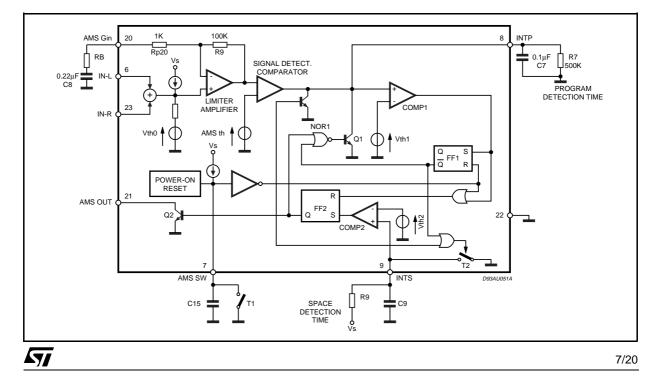
ELECTRICAL CHARACTERISTICS (continued) DOLBY SECTION

Symbol	Parameter	Test Condition	DOLBY	Min.	Тур.	Max.	Unit
B DEC 2	Decode Out	f = 500Hz; VI = -22.1dB	ON	-26.5	-25	-23.5	dB
B DEC 3	Decode Out	f = 2KHz; VI = -18dB	ON	-26.5	-25	-23.5	dB
B DEC 4	Decode Out	f = 5KHz; VI = -29.7dB	ON	-41.5	-40	-38.5	dB
B DEC 5	Decode Out	f = 10KHz; VI = -29.6dB	ON	-41.5	-40	-38.5	dB
NRı	Dolby ON Low Level Pin 19			0		0.8	V
NRh	Dolby OFF High Level Pin 19			2		Vs	V

GENERAL (PREAMPLIFIER + DOLBY)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
THD	Total Harmonic Dist.	$V_0 = 0$ dB; f = 1KHz Dolby OFF		0.02	0.1	%
		$V_O = 0dB$; f = 1KHz Dolby ON		0.05	0.1	%
		Vo = 0dB; f = 10KHz Dolby OFF		0.03		%
		$V_O = 0dB$; f = 10KHz Dolby ON		0.08		%
S/N	Signal to Noise Ratio	$R_g = 600\Omega$; $V_O = 0dB$; Unweighted; Dolby OFF		63		dB
		$R_g = 600\Omega$; $V_O = 0dB$; Unweighted; Dolby ON		70		dB
		$R_g = 600\Omega$; $V_O = 0dB$; CCIR/ARM; Dolby OFF	54	63		dB
		$R_g = 600\Omega$; $V_O = 0dB$; CCIR/ARM; Dolby ON	56	72		dB
Cs	Channel Separation	$R_g = 600\Omega$; f = 1KHz Dolby OFF	50	64		dB
		$R_g = 600\Omega$; f = 1KHz Dolby ON		70		dB
Ст	Channel Cross Talk	$R_g = 600\Omega$; f = 1KHz Dolby OFF	56	70		dB
		$R_g = 600\Omega$; f = 1KHz Dolby ON		75		dB

Figure 2: Audio Music Sensor



AUDIO MUSIC SENSOR (See Figure 2)

Aim of this section is to detect interprogram spaces present on a recorded tape.

Both the blanks (interprogram spaces) and the programs minimum detectable durations can be easily set by means of 2 external and independent time constants.

Also the minimum detectable input signal level can be externally adjusted, by a dedicated gain network.

Main blocks are:

- Variable gain limiter amplifier
- Signal detector circuitry
- Logic blocks able to avoid unproper operations.

Operations Description (refer to the simplified schematic of Figure 2).

- a)The two channels left and right mean signal coming from the preamp chain (AC coupled) are added (current) at the AMS input and presented to the limiter amplifier. The limiter amplifier gain is internally fixed to 40dB, and it could be reduced by the R8 external resistor. The AMSVth threshold is fixed at 1V. The following signal detector comparator informs of the presence of music signal (High level out) and avoids the erroneous detection of very low signal (like noise) as real program.
- b)The system moves in blank detection mode everytime the supply is turned on or, with power supplied, the AMS On/Off pin (to be driven by an open collector output) is turned off (T1 open). Once this condition has happened, the capacitor C15 charges, defining a minimum reset time, long enough to reset the Flip-Flops FF1 and FF2 and to descharge the program detector external C7 capacitor. The charging current at the AMS SW pin is about 10μ A. It follows that the reset time (C15 x Vpin7)/Ic15 is given approximately by 0.122 x C15 ns where C15 is in μ F.
- c)From now on where the sum input signal (leftright) amplified by the limiter exceeds the sig-

nal detector threshold (3) the capacitor C₇ is forced to charge. When the voltage across this capacitor reaches the comparator COMP1 threshold voltage Vth1 (approx. 2 Vbe) FF1 is set and FF2 is reset. (4) It follows that Q1 is turned on discharging the program detection capacitor (C7).

d)Always when there is a recorded zone, Q₁ is on; it becomes off only if a blank section is reached. When, with a time constant controlled by the R₉, C₉ network the voltage at space detection time pin reaches Vth₂ threshold (comparator COMP₂) a true blank section is detected and the FF₂ is set. (The minimum charging time is approximately given by:

0.69 x C9 x R9 [sec]

In this condition Q₂ is on, forcing the open collector AMS output to go low, informing the user that a true blank section has been detected. The state is then able to start from the above point c). Figures 3-4 show the signal behaviour.

The device is able to prevent false interspace detection and the end of the tape. (see Fig. 4).

Note:

(3): minimum RMS input signal is given by:

$$V_{in} = AMSVth \cdot \frac{1K + R_8}{101K + R_8} \cdot 0.6$$

where Vin is the mean of left and right channels::

$$V_{in} = \frac{V_{right} + V_{left}}{2}$$

(4): the charging current at pin 8 is about 20μA (half input signal) so program detection time constant is given by:

$$\frac{C_7 \times 2V_{be}}{20\mu A} = 70 \times C_7 \, [\mu F] = [msec]$$

It is recommended to insert a resistor (R7) high enough to prevent fast C7 capacitor discharging.





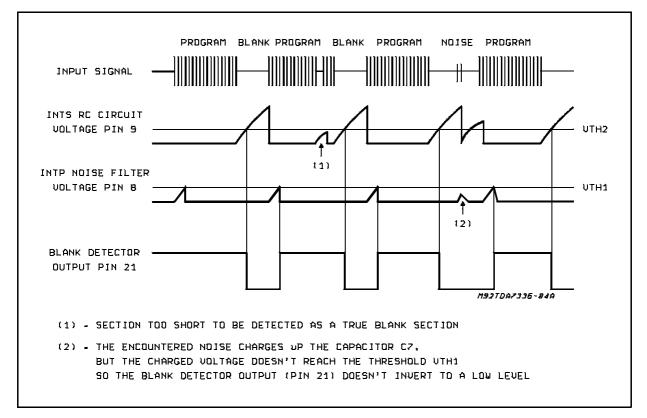
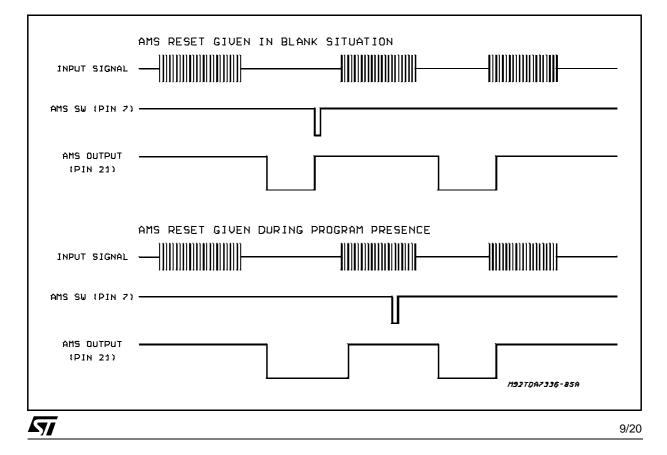


Figure 4



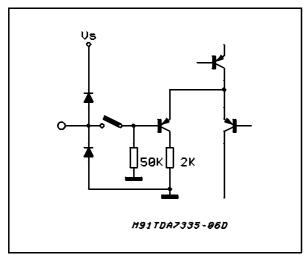
TDA7336

	COMPONENT	RECOMMENDED VALUE	PURPOSE
P R E A M P	TR1,TR2 C1, C2 C3, C4 R1, R2 R3, R5 R4, R6	1KΩ 1μF 10nF 1.2KΩ 6.8KΩ 300KΩ	Left/Right Channel IN/OUT equalizer filter TR fixes the gain 150msec NORMAL 70μsec METAL
	C5, C6	0.33μF ±10%	Preamplifier out to Dolby B input coupling capacitor
A	R8 C8	10ΚΩ 0.22μF	Define the AMS input threshold level $V_{in} \cdot \frac{101K + R_8}{1K + R_8} \cdot 1.5 > 1V$ where $V_{in} = (V_{right} + V_{left})/2$
M S	R7 C7	470KΩ 0.1μF	Set the interprogram detection time: INTP = $70 \times 10^{-3} \times C7[\mu F] = [sec]$
	R9 C9	100KΩ 1μF	Set the interspace detection time: INTS = $0.69 \times C_{9 \times} R_{9}$ sec
	C15	100nF	It fixes music search reset time; Tres = $0.122 \times C_{15}[\mu F]$ = [sec] if C ₁₅ expressed in μF
D	C10, C11	0.68µF ±10%	Dolby output coupling capacitors
D	C12, C13	4.7μF ±10%	Dolby time constants
L	C14	4.7μF	Reference voltage external capacitor
B Y	R11	43KΩ	It fixes the I _{ref} current
	C16 R16	0.1μF 30KΩ	If fixes the mute time (typ 10msec).

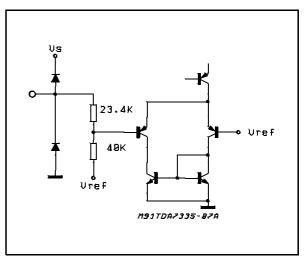
ELECTRICAL COMPONENT DESCRIPTION (see figure 1)

PINS DESCRIPTION: Internal Configuration

Figure 5: PINS: 2 - 27







PINS DESCRIPTION: Internal Configuration

Figure 7: PINS: 12 - 17

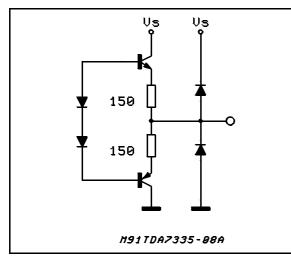
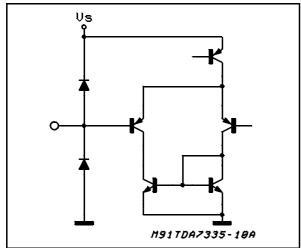
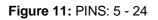
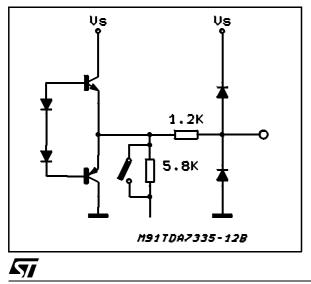
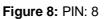


Figure 9: PINS: 3 - 26









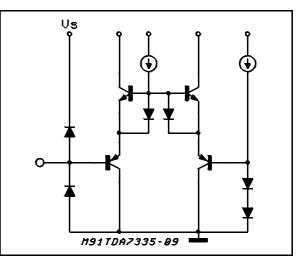
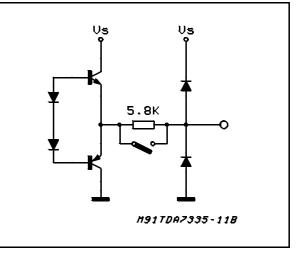
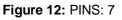
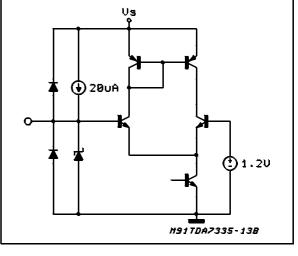


Figure 10: PINS: 4 - 25







TDA7336

PINS DESCRIPTION: Internal Configuration

Figure 13: PINS: 11 - 18

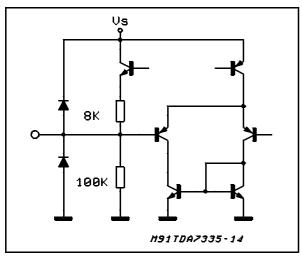
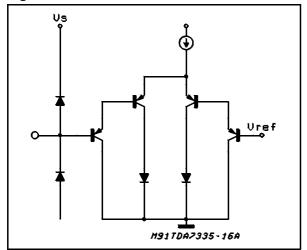
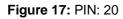


Figure 15: PIN: 9





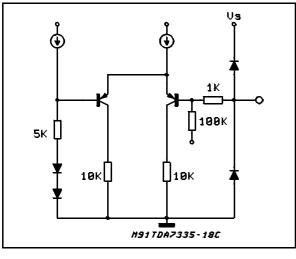
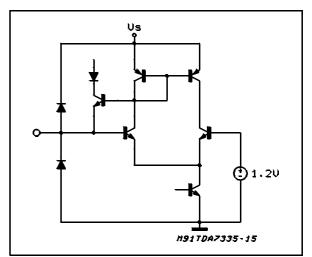
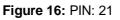
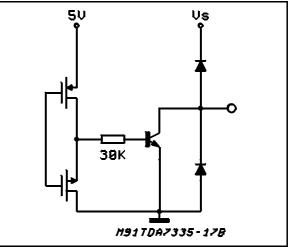


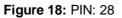


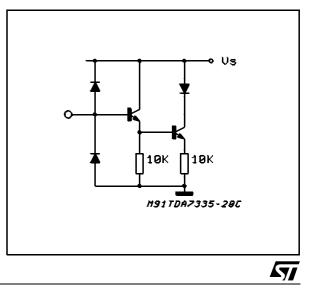
Figure 14: PIN: 13





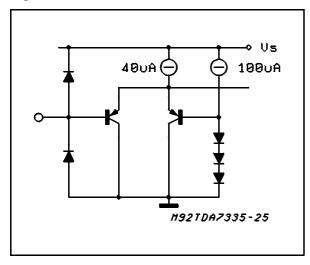






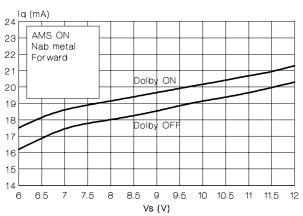
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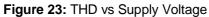
Figure 19: PIN: 19 - 10



DEVICE CHARACTERISTICS

Figure 21: Quiescent Current vs. Supply Voltage





Metal

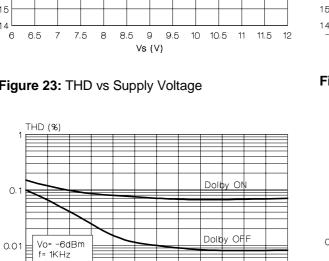
6.5

7 7.5 8

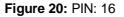
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6



8.5 9 Vs (V)



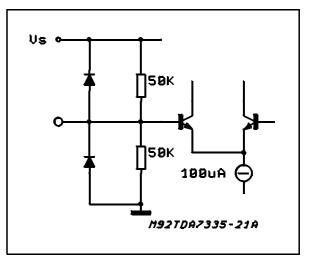
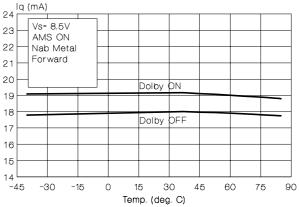
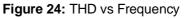
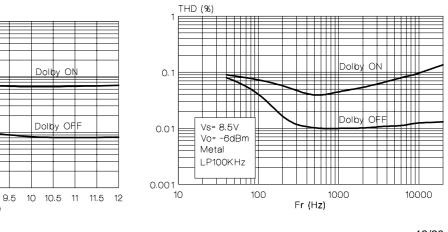


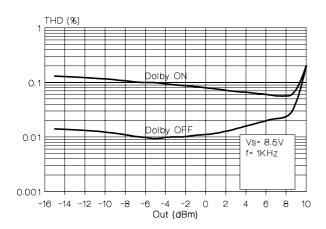
Figure 22: Quiescent Current vs. Temperature



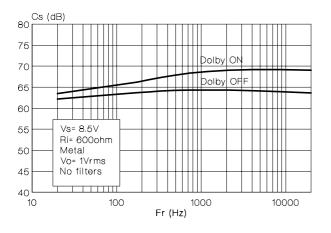




DEVICE CHARACTERISTICS (continued) **Figure 25:** THD vs. Output Signal









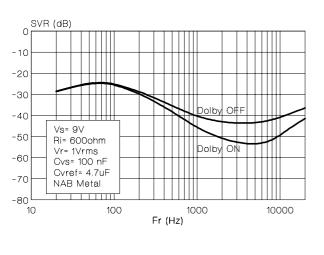
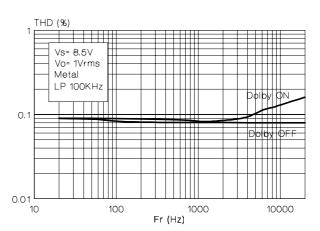
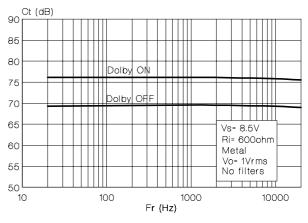


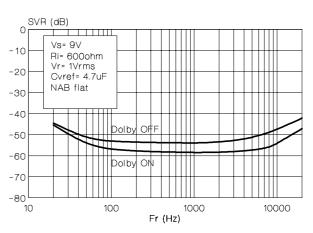
Figure 26: THD+N vs. Frequency











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DEVICE CHARACTERISTICS (continued)

Figure 31: Ripple Rejection vs. Frequency

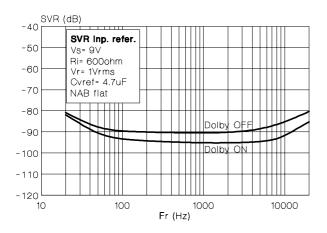


Figure 32: Mute Attenuation vs. Frequency

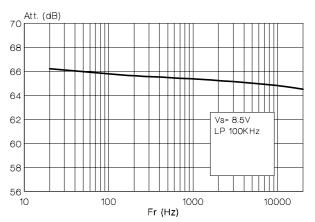
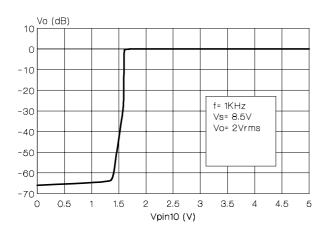
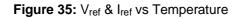


Figure 33: Mute Threshold





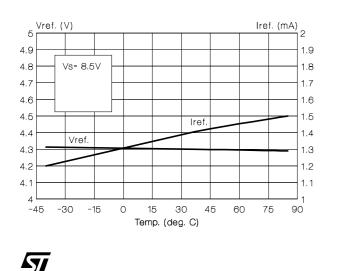


Figure 34: Vref & Iref vs Supply Voltage

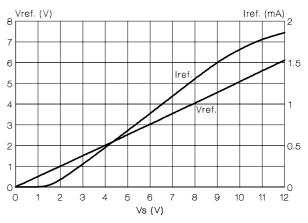
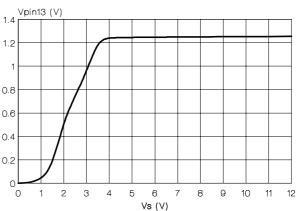


Figure 36: D.C. Voltage pin 13 vs. Supply Voltage



DEVICE CHARACTERISTICS (continued)

Figure 37: Equalizer Threshold

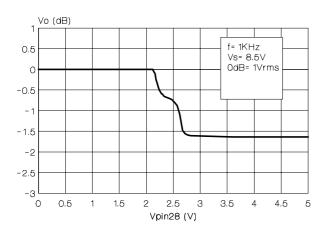


Figure38: Noise Reduction Threshold

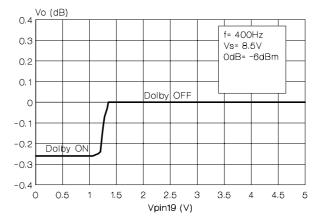


Figure 39: NAB Network

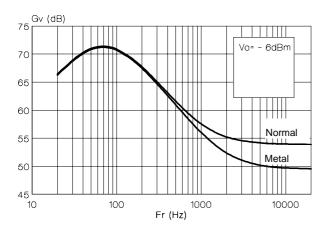


Figure 41: Signaling Handling vs. Supply Voltage

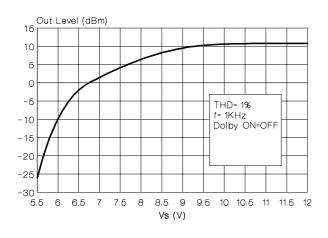


Figure 40: Load Characteristics

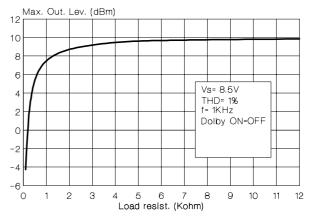
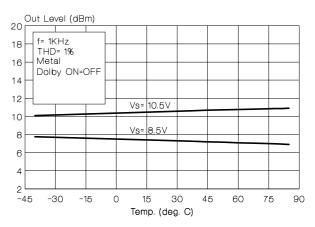


Figure 42: Signal Handling vs. Temperature



DEVICE CHARACTERISTICS (continued) **Figure 43:** AMS Threshold vs. Frequency

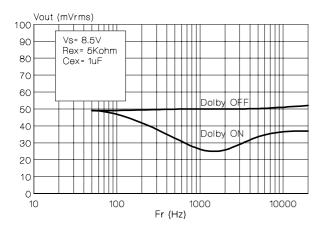


Figure 44: AMS Threshold vs. Rex

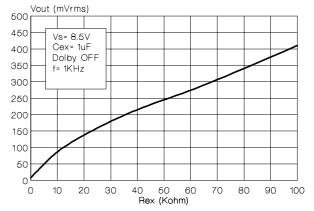


Figure 45: AMS Reset Time vs. Cex

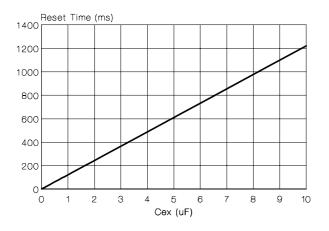
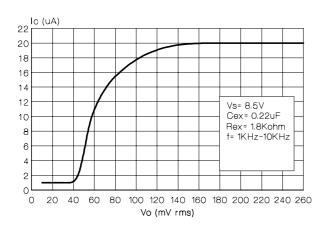
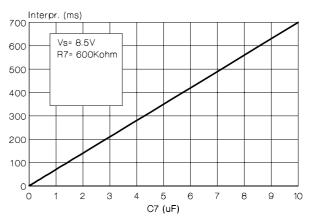


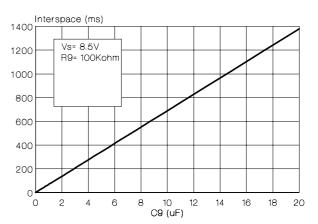
Figure 47: Interprogram Charging Current





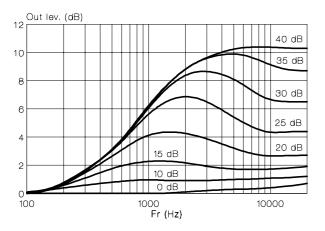






DEVICE CHARACTERISTICS (continued)

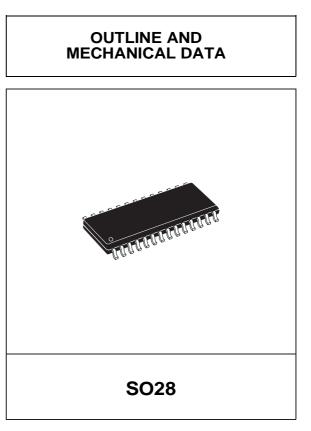
Figure 49: Dolby-B Table

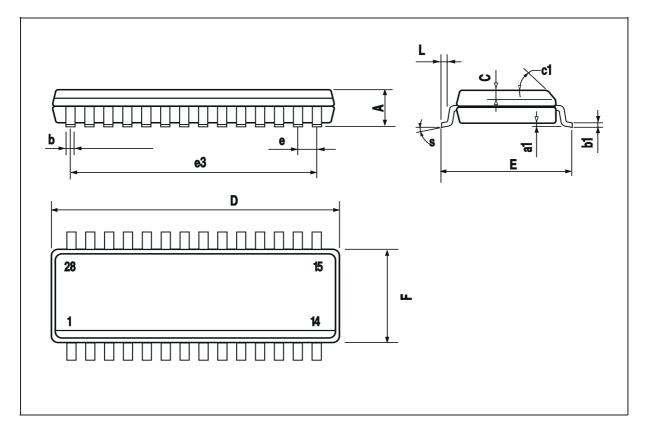






DIM.		mm		inch			
2	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			2.65			0.104	
a1	0.1		0.3	0.004		0.012	
b	0.35		0.49	0.014		0.019	
b1	0.23		0.32	0.009		0.013	
С		0.5			0.020		
c1			45° ((typ.)			
D	17.7		18.1	0.697		0.713	
E	10		10.65	0.394		0.419	
е		1.27			0.050		
e3		16.51			0.65		
F	7.4		7.6	0.291		0.299	
L	0.4		1.27	0.016		0.050	
S	8 ° (max.)						





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